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Vishay Semiconductor/Diodes Division VT1045BP-M3/4W

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VT1045BP-M3/4W - DIODE SCHOTTKY 45V 10A TO220AC

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Vishay General Semiconductor

VT1045BP

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.41$ V at $I_F = 5$ A

TMBS® TO-220AC 2 VT1045BP



PRIMARY CHARACTERISTICS			
I _{F(AV)}	10 A		
V _{RRM}	45 V		
I _{FSM}	100 A		
V_F at $I_F = 10 A$	0.52 V		
T _{OP} max. (AC mode)	150 °C		
T _J max. (DC forward current)	200 °C		
Package	TO-220AC		
Diode variation	Single die		

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
 FREE
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-220AC

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VT1045BP	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	45	V	
Maximum DC forward bypassing current (fig. 1)	I _{F(DC)} ⁽¹⁾	10	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	100	А	
Operating junction temperature range (AC mode)	T _{OP} -40 to +150		°C	
Junction temperature in DC forward current without reverse bias, $t \leq 1 \ h$	T _J ⁽²⁾	≤200	°C	

Notes

⁽¹⁾ With heatsink

(2) Meets the requirements of IEC 61215 ed.2 bypass diode thermal test

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 5 A	T _A = 25 °C	V _F (1)	0.50	-	V
	I _F = 10 A			0.57	0.68	
	I _F = 5 A	T _A = 125 °C		0.41	-	
	I _F = 10 A			0.52	0.64	
Reverse current	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	500	μA
		T _A = 125 °C		5	15	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	VT1045BP	UNIT	
Typical thermal resistance	$R_{ ext{ heta}JC}$	3.0	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AC	VT1045BP-M3/4W	1.87	4W	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

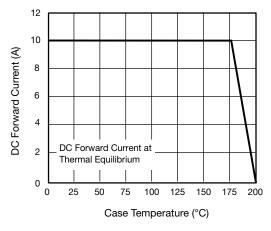


Fig. 1 - Maximum Forward Current Derating Curve

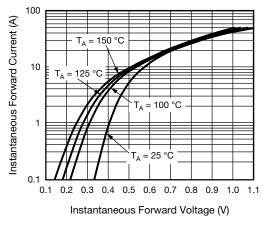


Fig. 2 - Typical Instantaneous Forward Characteristics

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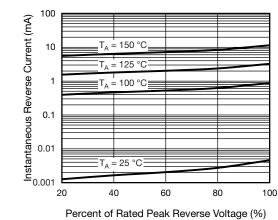


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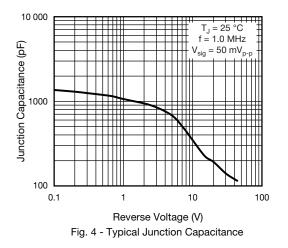


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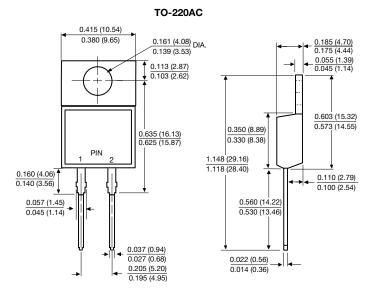
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ercent of Rated Peak Reverse Voltage (%) Fig. 3 - Typical Reverse Characteristics



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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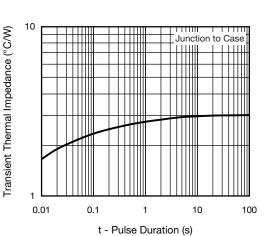


Fig. 5 - Typical Transient Thermal Impedance



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